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Correlation effects in charge-density wave insulator BaBiO<sub>3</sub> CESARE FRANCHINI, MARTIJN MARSMAN, GEORG KRESSE, Faculty of Physics, University of Vienna and Center for Computational Materials Science — The negative-U nature of BaBiO<sub>3</sub> leads to a charge-ordered insulating state in which pentavalent Bi<sup>5+</sup> coexists with trivalent Bi<sup>3+</sup>. Despite the apparent absence of strong-correlation effects in BaBiO<sub>3</sub> standard density functional (DFT) theory yields a much too small band gap of 0.14 eV. By means of an hybrid-DFT approach combined with self-consistent GW including vertex corrections we investigate the electronic, vibrational and dielectric properties of BaBiO<sub>3</sub>. We show that the inclusion of strong-correlation effects increases the band gap up to 1.2 eV, shifts the oxygen breathing modes upwards by  $\approx 2$  THz and reduces the dielectric constant by a factor of 3. The overall agreement with available experimental data is significantly improved.

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